



STTH30R06CW

TURBO 2 ULTRAFAST HIGH VOLTAGE RECTIFIER

MAIN PRODUCT CHARACTERISTICS

$I_{F(AV)}$	2 x 15 A
V_{RRM}	600 V
$I_{RM} (typ.)$	8 A
$T_j (max)$	175 °C
$V_F (max)$	1.8 V
$trr (max)$	50 ns

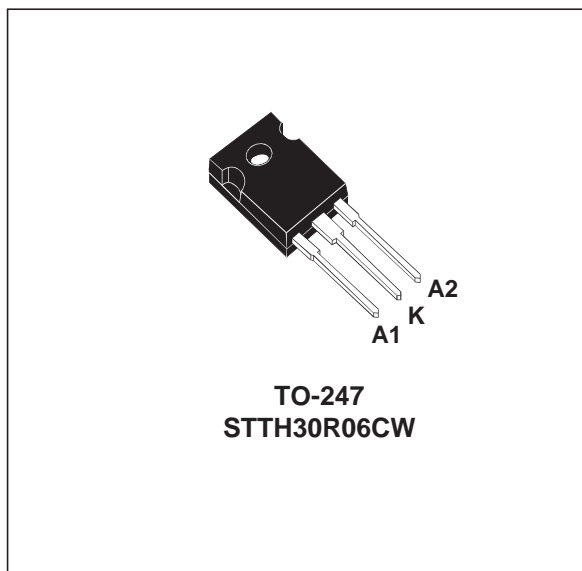
FEATURES AND BENEFITS

- Ultrafast switching
- Low reverse recovery current
- Reduces switching losses
- Low thermal resistance

DESCRIPTION

The STTH30R06CW, which is using ST Turbo 2 600V technology, is specially suited as boost diode in continuous mode power factor corrections and hard switching conditions.

The device is also intended for use as a free wheeling diode in power supplies and other power switching applications.



ABSOLUTE RATINGS (limiting values)

Symbol	Parameter		Value	Unit
V_{RRM}	Repetitive peak reverse voltage		600	V
$I_{F(RMS)}$	RMS forward current		30	A
$I_{F(AV)}$	Average forward current	Per diode Per device	15 30	A
I_{FSM}	Surge non repetitive forward current	tp = 10 ms Sinusoidal	120	A
T_{stg}	Storage temperature range		- 65 + 175	°C
T_j	Maximum operating junction temperature		175	°C

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THERMAL RESISTANCES

Symbol	Parameter		Value	Unit
$R_{th(j-c)}$	Junction to case	Per diode	1.5	°C/W
		Total	1.0	
$R_{th(c)}$		Coupling	0.5	

STATIC ELECTRICAL CHARACTERISTICS (per diode)

Symbol	Parameter	Tests conditions		Min.	Typ.	Max.	Unit
I_R	Reverse leakage current	$V_R = 600V$	$T_j = 25^\circ C$			60	μA
			$T_j = 125^\circ C$		70	800	
V_F	Forward voltage drop	$I_F = 15 A$	$T_j = 25^\circ C$			2.9	V
			$T_j = 125^\circ C$		1.4	1.8	

To evaluate the maximum conduction losses use the following equation :
 $P = 1.16 \times I_{F(AV)} + 0.043 I_{F(RMS)}^2$

DYNAMIC ELECTRICAL CHARACTERISTICS

Symbol	Tests conditions		Min.	Typ.	Max.	Unit
trr	$I_F = 0.5 A$ $I_{rr} = 0.25 A$ $I_R = 1 A$	$T_j = 25^\circ C$			30	ns
	$I_F = 1 A$ $di_F/dt = - 50 A/\mu s$ $V_R = 30V$				50	
I_{RM}	$V_R = 400 V$ $I_F = 15A$ $di_F/dt = - 200A/\mu s$	$T_j = 125^\circ C$		7.5	9.0	A
S factor				0.15		
Qrr				220		nC
tfr	$I_F = 15 A$ $di_F/dt = 120 A/\mu s$ $V_{FR} = 1.1 \times V_{Fmax}$	$T_j = 25^\circ C$			200	ns
V_{FP}					6	V

Fig. 1: Conduction losses versus average current (per leg).

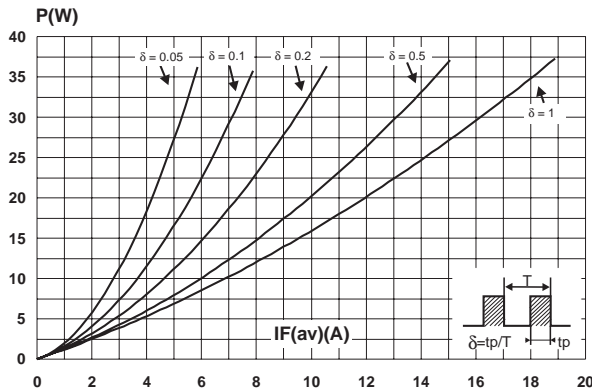


Fig. 2: Forward voltage drop versus forward current (per leg).

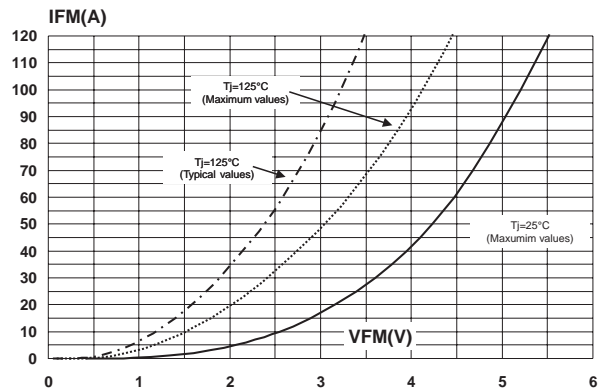


Fig. 3: Relative variation of thermal impedance junction to case versus pulse duration.

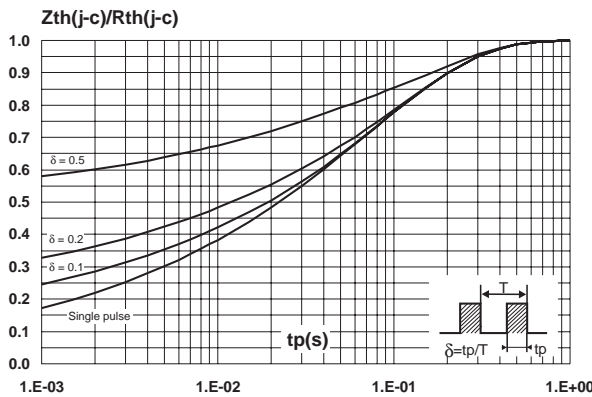


Fig. 4: Peak reverse recovery current versus dI_F/dt (90% confidence, per leg).

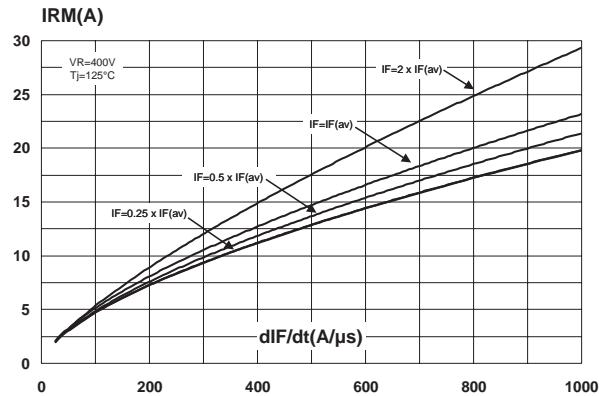


Fig. 5: Reverse recovery time versus dI_F/dt (90% confidence, per leg).

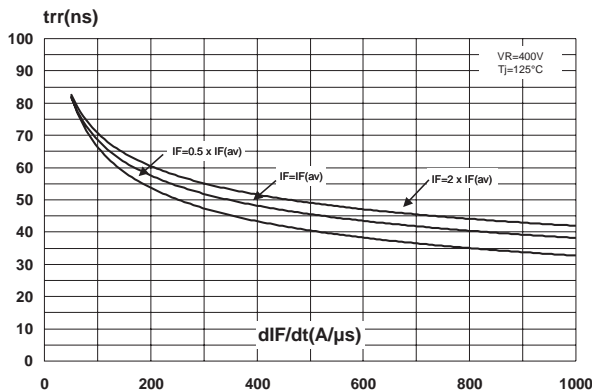


Fig. 6: Reverse recovery charges versus dI_F/dt (90% confidence, per leg).

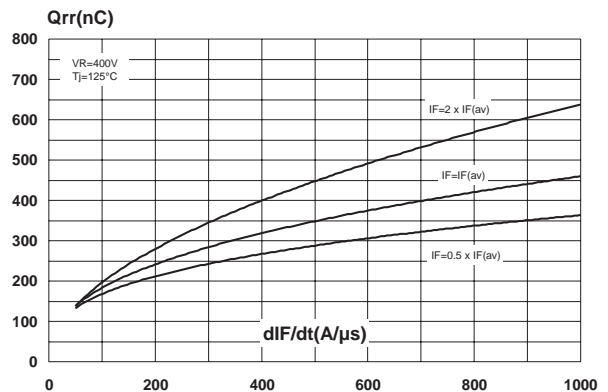


Fig. 7: Softness factor versus di_F/dt (typical values, per leg).

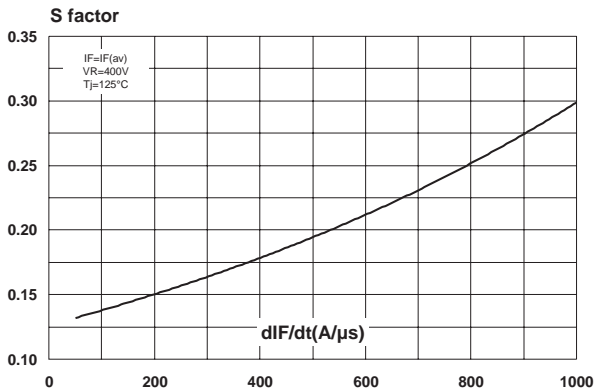


Fig. 8: Relative variation of dynamic parameters versus junction temperature.

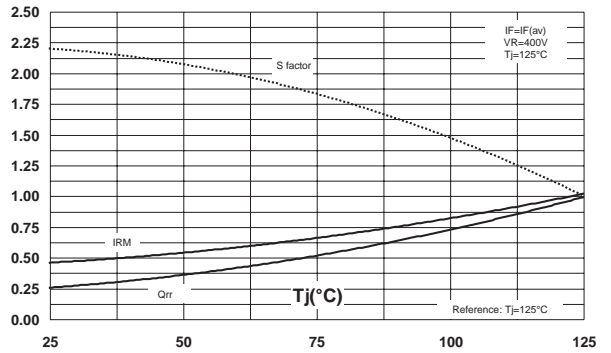


Fig. 9: Transient peak forward voltage versus di_F/dt (90% confidence, per leg).

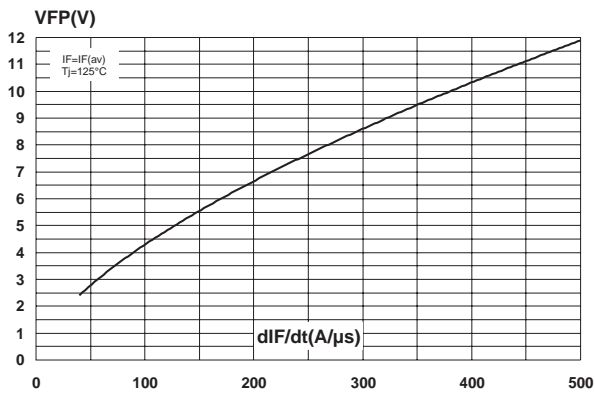


Fig. 10: Forward recovery time versus di_F/dt (90% confidence, per leg).

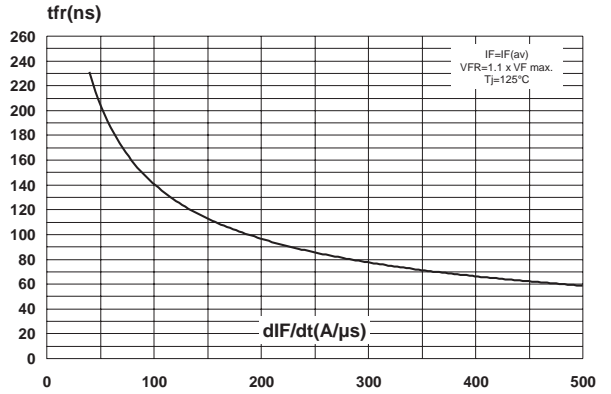
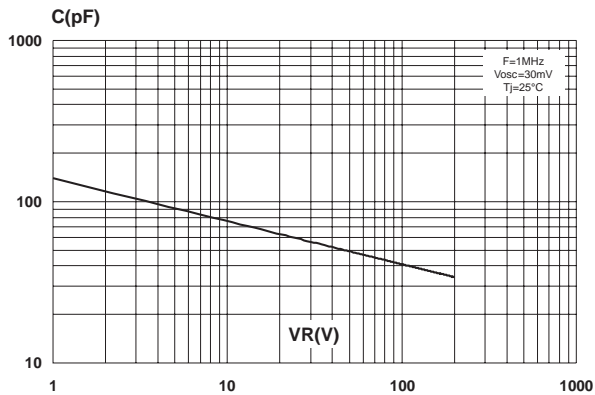
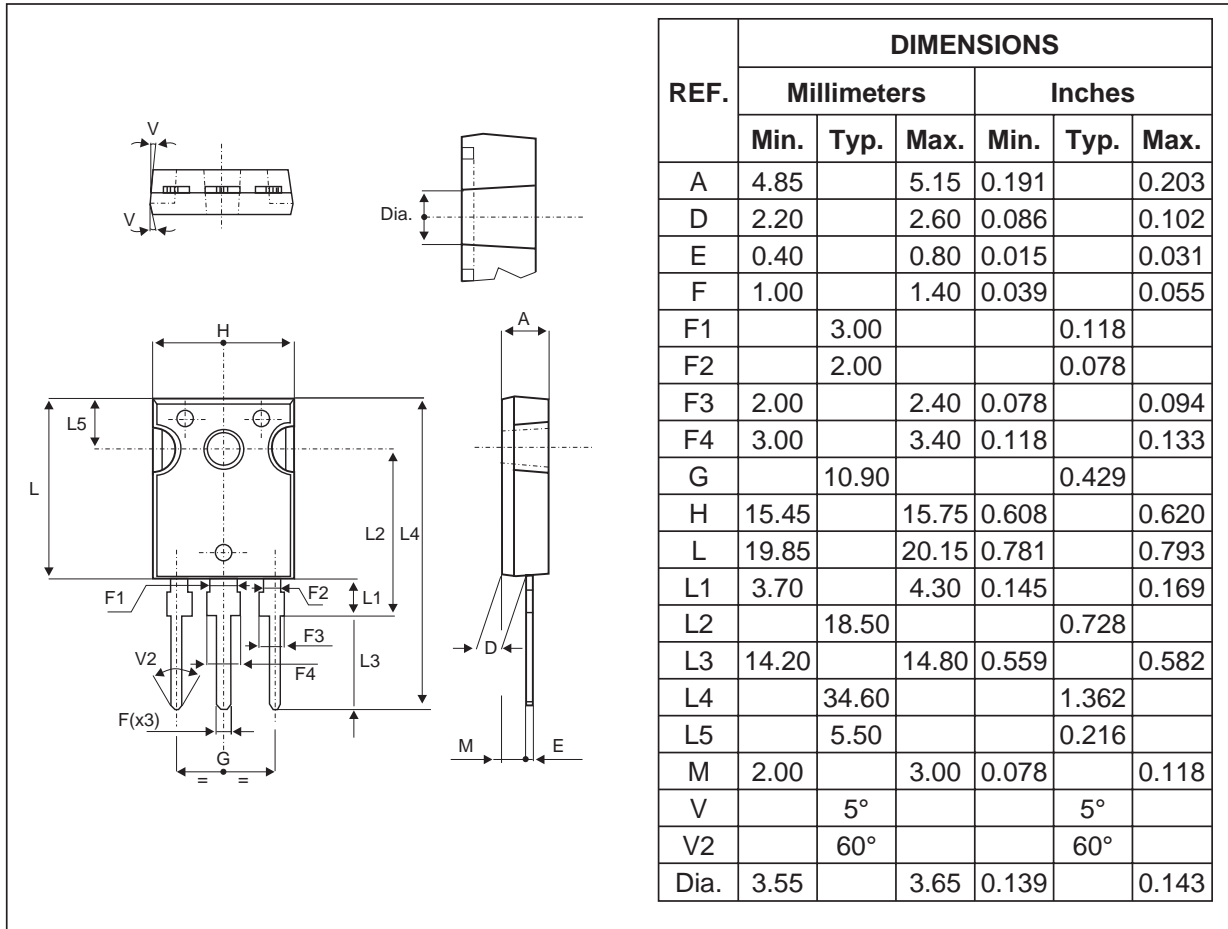


Fig. 11: Junction capacitance versus reverse voltage applied (typical values, per leg).



PACKAGE MECHANICAL DATA
TO-247



Ordering code	Marking	Package	Weight	Base qty	Delivery mode
STTH30R06CW	STTH30R06CW	TO-247	4.36 g	30	Tube

- Epoxy meets UL 94,V0

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